

Electronic Circuits II – Assignment 03

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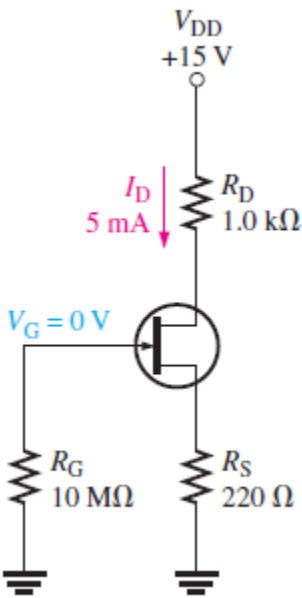
#	Student ID	Student Name	Grade (10)
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١. يتم تسليم التمرين محلولا في خلال أسبوع من تاريخ التمرين، و يتم حذف درجتين من التمرين عن كل أسبوع تأخير
٢. يتم التسليم لمعيد المقرر مباشرة
٣. تتم أجابه التمرين في نفس ورق الأسئلة

#		
1	The JFET always operates with a reverse-biased gate-to-source pn junction.	
2	The channel resistance of a JFET is a constant.	
3	The gate-to-source voltage of an n -channel JFET must be negative.	
4	I_D becomes zero at the pinch-off voltage.	
5	V_{GS} has no effect on I_D .	
6	$V_{GS(off)}$ and V_P are always equal in magnitude but opposite in polarity.	
7	The JFET is a square-law device because of the mathematical expression of its transfer characteristic curve	
8	Forward transconductance is the change in drain voltage for a given change in gate voltage.	

MCQ

#	Question	
1	<p>If the drain current in Figure 8-17 is increased, V_{DS} will</p>  <p>(a) increase (b) decrease (c) not change</p>	



2	<p>If the drain current in Figure is increased, V_{GS} will</p> <p>(a) increase (b) decrease (c) not change</p>	
3	<p>For $V_{GS} = 0$ V, the drain current becomes constant when V_{DS} exceeds</p> <p>(a) cutoff (b) V_{DD} (c) V_P (d) 0 V</p>	
4	<p>The constant-current region of a FET lies between</p> <p>(a) cutoff and saturation (b) cutoff and pinch-off (c) 0 and I_{DSS} (d) pinch-off and breakdown</p>	
5	<p>In a certain FET circuit, $V_{GS} = 0$ V, $V_{DD} = 15$ V, $I_{DSS} = 15$ mA, and $R_D = 470$ Ω. If R_D is decreased to 330 Ω, I_{DSS} is</p> <p>(a) 19.5 mA (b) 10.5 mA (c) 15 mA (d) 1 mA</p>	
6	<p>At cutoff, the JFET channel is</p> <p>(a) at its widest point (b) completely closed by the depletion region (c) extremely narrow (d) reverse-biased</p>	

